



PxxxxSD Series

Rev.2.0

DEDRIPTION:

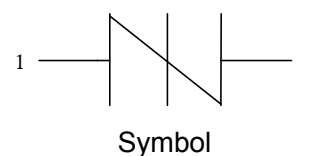
PxxxxD series thyristors are a type of semi-conduct component. They are designed to protect baseband equipment from damaging overvoltage transients. such as modems, telephones, line cards, answering machines, FAX machines, T1/E1, xDSL and more.



SMB

FEATURES:

- ✧ Excellent capability of absorbing transient surge
- ✧ Quick response to surge voltage (ns Level)
- ✧ Eliminates overvoltage caused by fast rising transients
- ✧ Moisture sensitivity level: Level 1
- ✧ Non degenerative

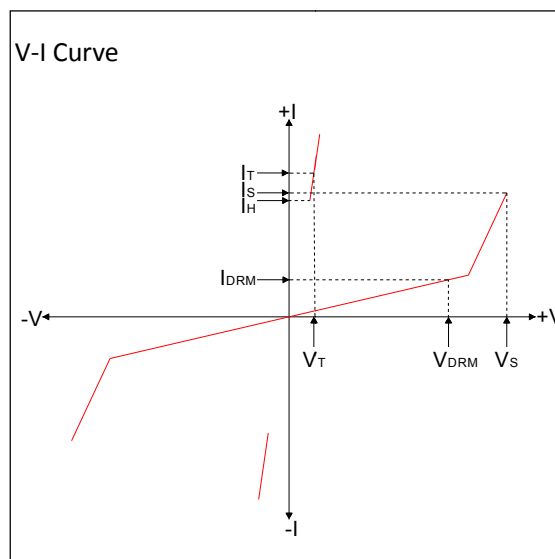


ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$, RH=45%-75%, unless otherwise noted)

Parameter	Symbol	Value	Unit
Storage temperature range	T_{stg}	-60 to +150	$^{\circ}\text{C}$
Operating junction temperature range	T_j	-40 to +125	$^{\circ}\text{C}$
Repetitive peak pulse current	I_{PP}	200	A

ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$)

Symbol	Parameter
V_{DRM}	Peak off-state voltage
I_{DRM}	Off-state current
V_S	Switching voltage
I_S	Switching current
V_T	On-state voltage
I_T	On-state current
I_H	Holding current
C_O	Off-state capacitance



ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$, continued)

Part Number	$I_{\text{DRM}}@V_{\text{DRM}}$		$V_S^{①}@I_S$		$V_T@I_T$		I_H	$C_O^{②}$	Marking
	μA	V	V	mA	V	A	mA	pF	
	max		max	max	max	max	min	max	
P0080SD	5	6	25	800	4	2.2	50	150	P-8D
P0640SD	5	58	77	800	4	2.2	50	150	P06D
P0720SD	5	65	87	800	4	2.2	50	150	P07D
P0900SD	5	75	98	800	4	2.2	50	140	P09D
P1100SD	5	90	130	800	4	2.2	50	110	P11D
P1300SD	5	120	160	800	4	2.2	50	100	P13D
P1500SD	5	140	180	800	4	2.2	50	90	P15D
P1800SD	5	170	220	800	4	2.2	50	90	P18D
P2300SD	5	190	260	800	4	2.2	50	80	P23D
P2600SD	5	220	300	800	4	2.2	50	70	P26D
P3100SD	5	275	350	800	4	2.2	50	60	P31D
P3500SD	5	320	400	800	4	2.2	50	60	P35D
P3800SD	5	340	450	800	4	2.2	50	60	P38D

① V_S is measured at 100KV/s② Off-state capacitance is measured in $V_{\text{DC}}=2\text{V}$, $V_{\text{RMS}}=1\text{V}$, $f=1\text{MHz}$

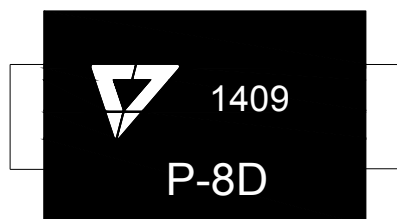
SURGE RATINGS

Series	I_{PP} (A) min			
	2×10us	8×20us	10×360us	10×1000us
D	1000	800	---	200

ORDERING INFORMATION

P	008	0	S	D
Series code P: SIDACtor	Median voltage	0: Bi-direction 1: Uni-direction	Package type	Surge ratings:8KV(10/700μs)

MARKING



P-8D : Device Marking Code
1409: In ninth week, 2014

SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see FIG.2)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150°C
	-Temperature Max($T_{s(max)}$)	+200°C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3°C/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T_L) (Liquid us)	+217°C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp (T_P)		8 min. Max
Do not exceed		+260°C

FIG.1: tr × td pulse waveform

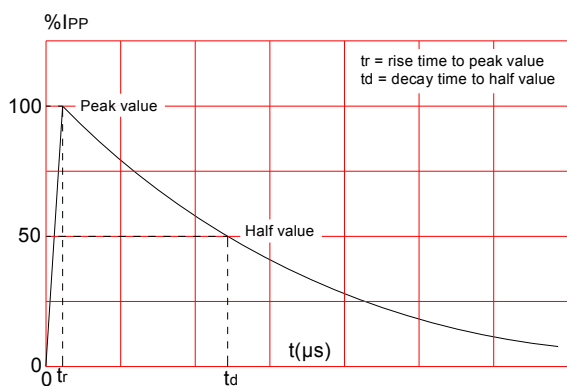


FIG.2: Reflow condition

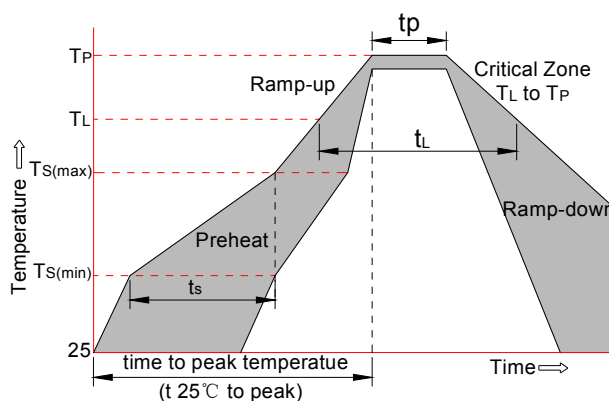
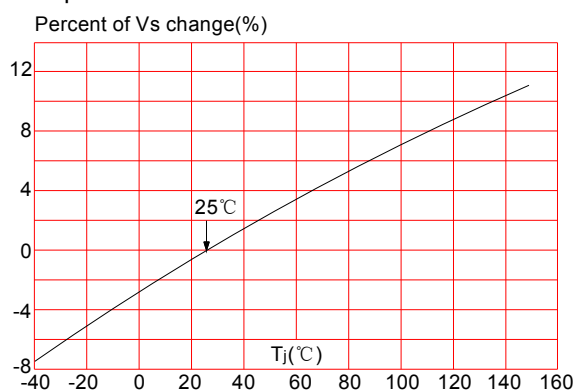
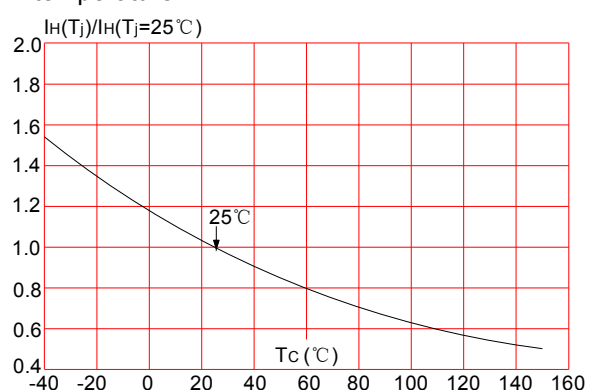
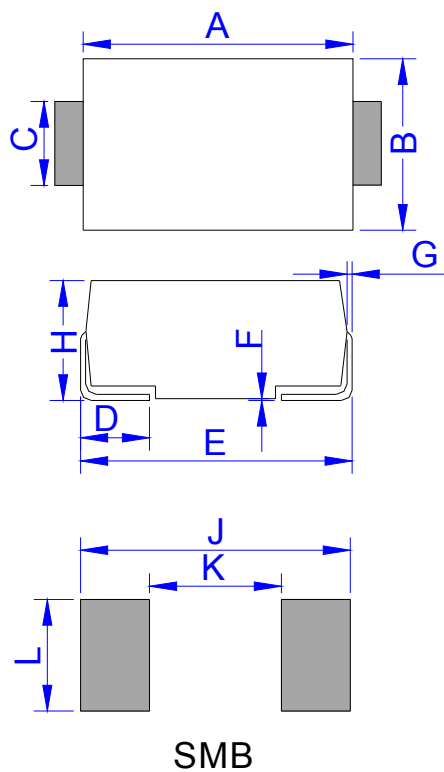
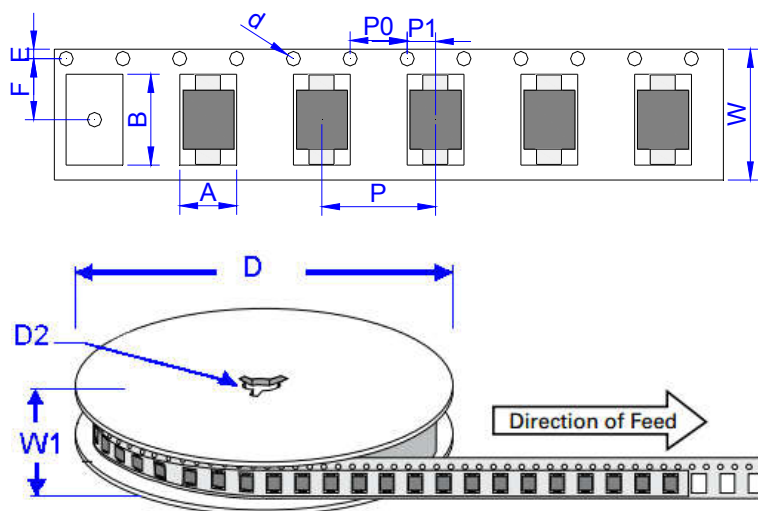


FIG.3: Normalized V_s change vs. junction temperature**FIG.4:** Normalized DC holding current vs. case temperature**PACKAGE MECHANICAL DATA**

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.25	4.75	0.167	0.187
B	3.30	3.94	0.130	0.155
C	1.85	2.25	0.073	0.087
D	0.76	1.52	0.030	0.060
E	5.21	5.59	0.205	0.220
F	0.051	0.203	0.002	0.008
G	0.15	0.31	0.006	0.012
H	2.15	2.45	0.085	0.097
J	6.80		0.268	
K		2.60		0.102
L	2.40		0.094	

TAPE AND REEL SPECIFICATION-SMB



Ref.	Dimensions	
	Millimeters	Inches
A	3.65 ± 0.3	0.144 ± 0.012
B	5.69 ± 0.3	0.244 ± 0.012
d	1.5 ± 0.1	0.059 ± 0.004
D	330.0	13.0
D2	13 ± 0.3	0.512 ± 0.012
E	1.5 ± 0.2	0.059 ± 0.008
F	5.65 ± 0.2	0.222 ± 0.008
P	8.0 ± 0.2	0.315 ± 0.008
P0	4.0 ± 0.2	0.157 ± 0.008
P1	2.0 ± 0.2	0.079 ± 0.008
W	12.0 ± 0.2	0.472 ± 0.008
W1	16.8 ± 2.0	0.661 ± 0.079

OUTLINE	REEL (PCS)	PER CARTON (PCS)	REEL DIAMETERS (mm)
TAPING	3,000	48,000	330

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